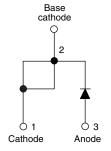


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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 20 A





60 ns

150 °C

Single die

0.6

TO-220AC FULL-PAK

 T_J max.

Diode variation

Snap factor

TO-220FP
20 A
200 V, 400 V, 600 V
1.3 V
300 A

FEATURES

- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC-JESD47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Material categorization:
 For definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	20	A			
V_{RRM}		200 to 600	V			
I _{FSM}		300	А			
V _F	10 A, T _J = 25 °C	1.2	V			
t _{rr}	1 A, 100 A/μs	60	ns			
T _J		- 40 to 150	°C			

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-20ETF02FPPbF, VS-20ETF02FP-M3	200	300				
VS-20ETF04FPPbF, VS-20ETF04FP-M3	400	500	5			
VS-20ETF06FPPbF, VS-20ETF06FP-M3	600	700				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 51 °C, 180° conduction half sine wave	20			
Maximum peak one cycle non-repetitive	l	10 ms sine pulse, rated V _{RRM} applied	250	Α		
surge current	IFSM	10 ms sine pulse, no voltage reapplied	300			
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s		
Maximum I-t for fusing	I-t	10 ms sine pulse, no voltage reapplied	442	A-5		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s		



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ISHAY	V3-2
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.30	V
		60 A, T _J = 25 °C		1.67	V
Forward slope resistance	r _t	T _J = 150 °C		12.5	mΩ
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.9	V
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
		T _J = 150 °C		5.0	

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	1
Reverse recovery time	t _{rr}	I _F at 20 Apk	160	ns	I _{FM} t
Reverse recovery current	I _{rr}	100 A/μs	10	Α	$t_a \mid t_b$
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC	dir/Q,,,
Snap factor	S	Typical	0.6		dt I _{RM(REC)}

THERMAL - MECH	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and stemperature range	orage	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistar junction to case	nce,	R_{thJC}	DC operation	2.5		
Maximum thermal resistar junction to ambient	nce,	R_{thJA}		62	°C/W	
Typical thermal resistance case to heatsink) ,	R _{thCS}	Mounting surface, smooth and greased	0.5		
Annuavimenta weight				2	g	
Approximate weight				0.07	OZ.	
minimun				6 (5)	kgf ⋅ cm	
Mounting torque maxin	maximum			12 (10)	(lbf · in)	
Marking device				20ETF	02FP	
			Case style TO-220 FULL-PAK	20ETF	04FP	
				20ETF	06FP	

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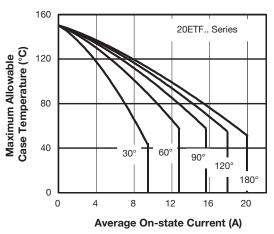


Fig. 1 - Current Rating Characteristics

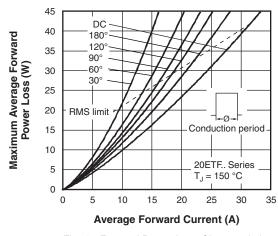


Fig. 4 - Forward Power Loss Characteristics

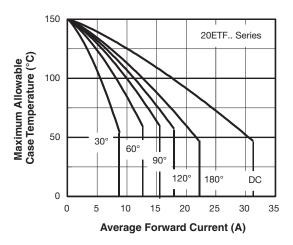


Fig. 2 - Current Rating Characteristics

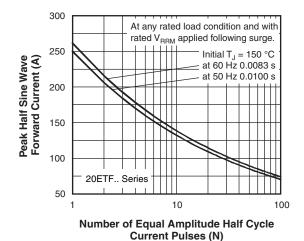


Fig. 5 - Maximum Non-Repetitive Surge Current

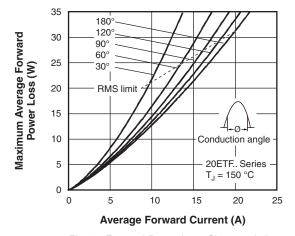


Fig. 3 - Forward Power Loss Characteristics

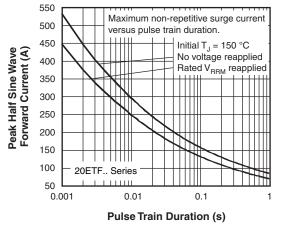


Fig. 6 - Maximum Non-Repetitive Surge Current



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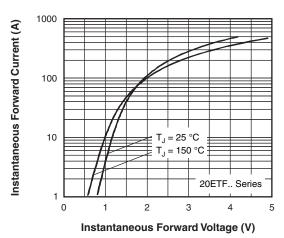


Fig. 7 - Forward Voltage Drop Characteristics

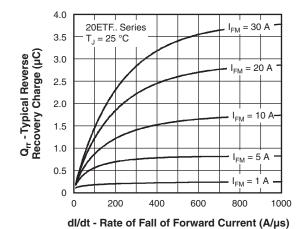


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

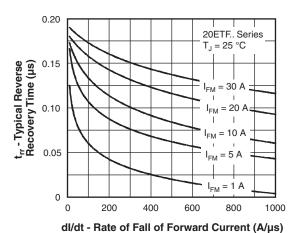


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

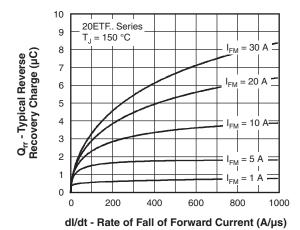


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

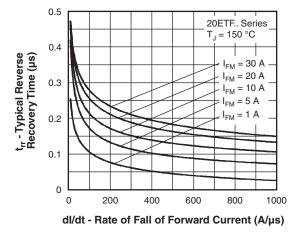


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

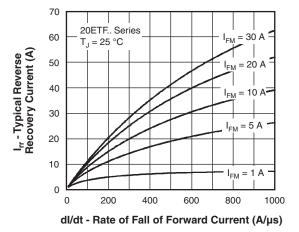


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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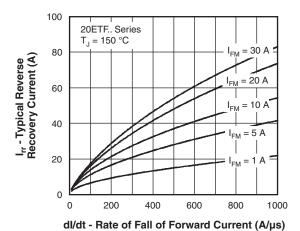


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

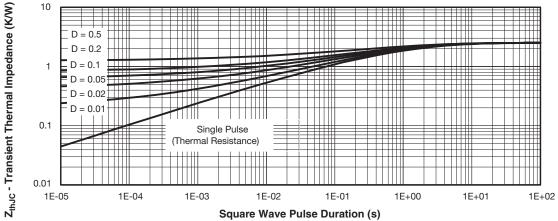
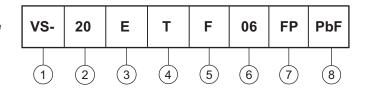


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Circuit configuration:

E = Single diode

4 - Package:

T = TO-220

5 - Type of silicon:

F = Fast soft recovery rectifier

02 = 200 V 04 = 400 V

Voltage code x 100 = V_{RRM}

06 = 600 V

7 - FULL-PAK

8 - Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

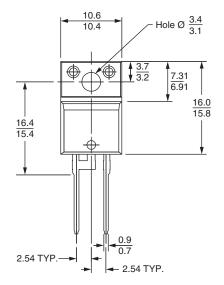
• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

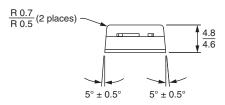
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20ETF02FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF02FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETF04FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF04FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETF06FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF06FP-M3	50	1000	Antistatic plastic tubes		

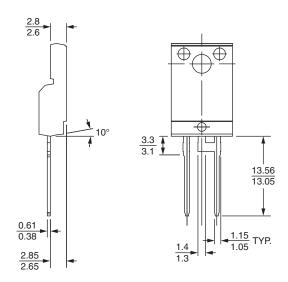
LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95005		
Doub monding information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		
SPICE model		www.vishay.com/doc?95410		

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DIMENSIONS in millimeters







Lead assignments

Diodes

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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